

# Content

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<b>Abstract ( in Chinese )</b>	I
<b>Abstract ( in English )</b>	III
<b>Acknowledgment</b>	VI
<b>Contents</b>	VII
<b>Figure Captions</b>	X
<b>Table Captions</b>	XVII
<b>Chapter 1: Introduction</b>	1
1.1 Motivation.....	2
1.2 PIN laser.....	4
1.3 History of vertical Cavity Surface Emitting lasers VCSEL).....	5
1.4 Overview and Dissertation.....	6
Reference .....	8
<b>Chapter 2: Molecular Beam Epitaxial Growth of InAs Quantum dot</b>	16
2.1 MBE Introduction.....	14
2.2 SK mode growth of InA/GaAs quantum dots by MBE.....	16
2.3 The effect of InAs growth rate.....	17
2.4 V/III ratio of InAs QDs.....	19
2.5 Quantum Dot cover by Quantum Well (Dot inWell) structure.....	20
2.6 InAs QDs cover by InGaAs QW.....	21
2.7 Optical emission range of InAs/InGaAs/GaAs quantum dot active region .....	22

2.8 InAs QDs cover with InAlAs strain reduce layer .....	24
--	----

Reference .....	28
-----------------	----

<b>Chpater 3: QD lasers.....</b>	<b>47</b>
----------------------------------	-----------

3.1 InAs/GaAs quantum dot edge emitting lasers.....	48
---	----

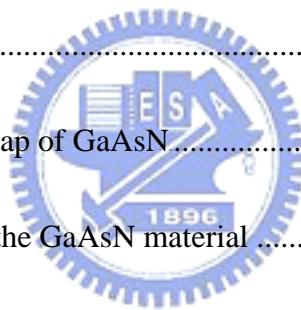
3.2 The vertical coupled InAs/GaAs quantum dot lasers.....	51
--	----

3.3 InAs QDs fully doped VCSELs.....	54
--------------------------------------	----

Reference .....	57
-----------------	----

<b>Chapter 4: Molecular Beam Epitaxy Growth of (Ga,In),(As,N,Sb) .....</b>	<b>75</b>
--	-----------

4.1 Nitrogen RF plasma .....	75
------------------------------	----



4.2 Nitrogen effect of the Bandgap of GaAsN.....	76
--	----

4.3 RF plasma optimization on the GaAsN material .....	77
--	----

4.4 MBE growth conditions for GaAsN .....	79
---	----

<i>4.41 Effect of growth temperature and growth rate.....</i>	<i>80</i>
---	-----------

<i>4.42 Effect of annealing.....</i>	<i>81</i>
--------------------------------------	-----------

4.5 MBE growth of InGaAsN/GaAs quantum well material.....	82
---	----

4.6 Improving PL of InGaAsN/GaAs quaternary alloy by thermal annealing.....	83
---	----

4.7 Optimizing the photoluminescence of InGaAsN/GaAs quantum well.....	84
--	----

4.8 The effect of Sb in InGaAs(N)/GaAs multiple quantum well.....	87
---	----

Reference .....	91
-----------------	----

<b>Chapter 5: InGaAsN/GaAs lasers.....</b>	121
5.1 High power InGaAsN/GaAs edge emitting lasers.....	121
5.2 InGaAsN/GaAs Intra-cavity contacted VCSEL.....	126
Reference.....	129
<b>Chapter 6: Summary.....</b>	147
<b>Curriculum Vita.....</b>	149
<b>Publication List.....</b>	150

